

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	8	pfet near10 perpendicular near10 nfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 10:54
L2	7	pfet near10 (source or drain or source/drain) near10 perpendicular near10 nfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 10:55
L3	7	((p near2 fet) or pfet) near10 (source or drain or source/drain) near10 perpendicular near10 (nfet or (n near fet))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 10:56
L4	7	((p near2 fet) or pfet) near10 (source or drain or source/drain) near10 perpendicular near10 (nfet or (n near2 fet))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 10:56
L5	7	((p near2 fet) or pfet) with (source or drain or source/drain) with perpendicular with (nfet or (n near2 fet))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 10:57
L6	7	((p near2 (fet or (field adj effect adj transistor))) or pfet) with (source or drain or source/drain) with perpendicular with (nfet or (n near2 fet))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 10:58
L7	8	((p near2 (fet or (field adj effect adj transistor))) or pfet) with (source or drain or source/drain) with perpendicular with (nfet or (n near2 (fet or (field adj effect adj transistor))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 11:01
L8	16	((p near2 (fet or (field adj effect adj transistor))) or pfet) with perpendicular with (nfet or (n near2 (fet or (field adj effect adj transistor))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 11:07
L9	0	("2005/0001290").URPN.	USPAT	OR	ON	2005/10/30 11:04
L10	363	(fet or (field adj effect adj transistor)) near10 perpendicular	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 11:07

L11	126	(fet or (field adj effect adj transistor)) near10 (source or drain or source/drain) near10 perpendicular	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 11:07
L12	132	(pfet or p-fet or nfet or n-fet or fet or (field adj effect adj transistor)) near10 (source or drain or source/drain) near10 perpendicular	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 11:08
L13	34	((pfet or p-fet or nfet or n-fet or fet or (field adj effect adj transistor)) near10 (source or drain or source/drain) near10 perpendicular).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 11:14
L14	5	((pfet or p-fet or nfet or n-fet or fet or (field adj effect adj transistor)) near10 (source or drain or source/drain) near10 perpendicular).clm. and (nfet and pfet)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/30 11:15